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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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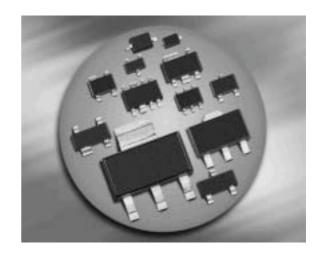




### Silicon Switching Diode

- For high-speed switching applications
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101





### **SMBD914/MMBD914**



Туре	Package	Configuration	Marking
SMBD914/MMBD914	SOT23	single	s5D

**Maximum Ratings** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V <sub>R</sub>	100	V
Peak reverse voltage	$V_{RM}$	100	
Forward current	I <sub>F</sub>	250	mA
Non-repetitive peak surge forward current	I <sub>FSM</sub>		Α
$t = 1 \mu s$		4.5	
t = 1  s		0.5	
Total power dissipation	P <sub>tot</sub>	370	mW
<i>T</i> <sub>S</sub> ≤ 54°C			
Junction temperature	T <sub>i</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-65 150	

### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	≤ 260	K/W
SMBD914/MMBD914			

1

<sup>&</sup>lt;sup>1</sup>Pb-containing package may be available upon special request

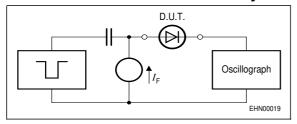
<sup>&</sup>lt;sup>2</sup>For calculation of *R*<sub>thJA</sub> please refer to Application Note Thermal Resistance



**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	Γ	I			
Breakdown voltage	$V_{(BR)}$	100	-	-	V
$I_{(BR)} = 100 \mu\text{A}$					
Reverse current	I <sub>R</sub>				μΑ
$V_{R} = 20 \text{ V}$		-	-	0.025	
$V_{\rm R} = 75 \text{ V}$		-	-	0.1	
$V_{R} = 20 \text{ V}, T_{A} = 150 ^{\circ}\text{C}$		-	-	30	
$V_{R} = 75 \text{ V}, T_{A} = 150 ^{\circ}\text{C}$		-	-	50	
Forward voltage	V <sub>F</sub>				mV
$I_{F} = 1 \; mA$		-	-	715	
$I_{\rm F} = 10  \text{mA}$		-	-	855	
$I_{F} = 50 \; mA$		-	-	1000	
$I_{\rm F} = 100  {\rm mA}$		-	-	1200	
$I_{\rm F} = 150 \text{ mA}$		-	-	1250	
AC Characteristics					
Diode capacitance	C <sub>T</sub>	-	-	2	pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$					
Reverse recovery time	t <sub>rr</sub>	-	-	4	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 10 mA, measured at $I_{\rm R}$ = 1mA ,					
$R_{L}$ = 100 $\Omega$					

## Test circuit for reverse recovery time



Pulse generator:  $t_p$  = 100ns, D = 0.05,  $t_r$  = 0.6ns,  $R_i$  = 50 $\Omega$ 

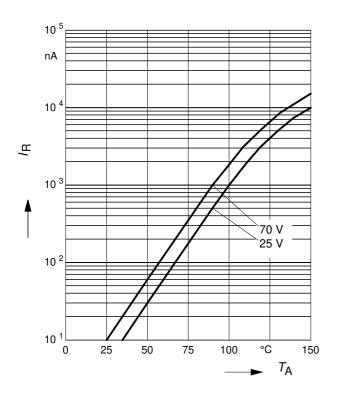
Oscillograph:  $R = 50\Omega$ ,  $t_r = 0.35$ ns,  $C \le 1$ pF

2 2007-03-28



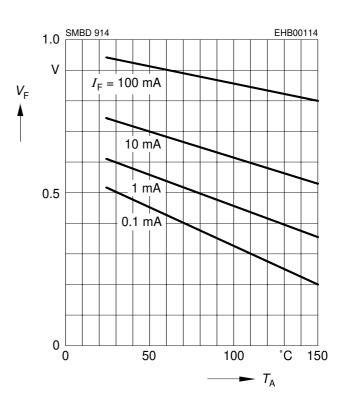
# Reverse current $I_R = f(T_A)$

 $V_{R}$  = Parameter



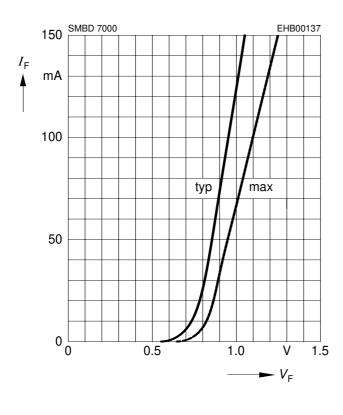
# Forward Voltage $V_F = f(T_A)$

 $I_{\rm F}$  = Parameter



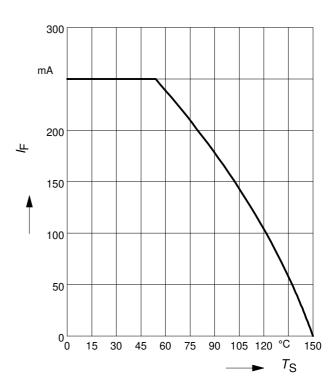
# Forward current $I_F = f(V_F)$

 $T_A = 25^{\circ}C$ 



Forward current  $I_F = f(T_S)$ 

SMBD914/MMBD914



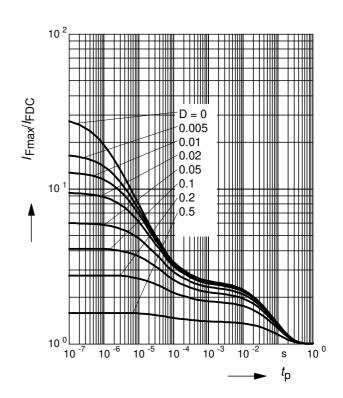


# Permissible Puls Load $R_{thJS} = f(t_p)$

# N/W 10 2 10 1 10 0 10 0.5 0.2 0.1 0.05 0.02 0.01 0.005 0.02 0.01 0.005 D = 0 tp

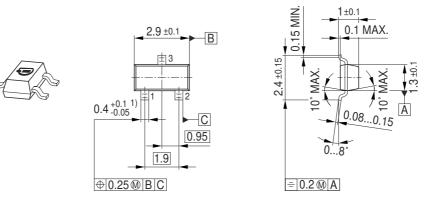
### **Permissible Pulse Load**

$$I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$$

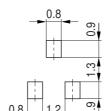




## Package Outline

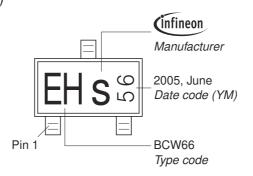


Foot Print



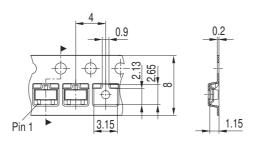
1) Lead width can be 0.6 max. in dambar area

## Marking Layout (Example)



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



5



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6